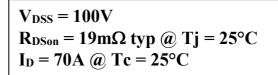
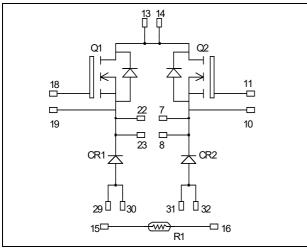
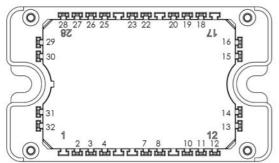


Dual Buck chopper **MOSFET Power Module**







All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Power MOS V® MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
 - Kelvin source for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a single buck of twice the current capability
- **RoHS** Compliant

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (per MOSFET)

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Voltage		100	V
Ţ		$T_c = 25$ °C	70	
I_D	Continuous Drain Current	$T_c = 80^{\circ}C$	50	A
I_{DM}	Pulsed Drain current		300	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		21	$m\Omega$
P_D	Power Dissipation $T_c = 25^{\circ}C$		208	W
I_{AR}	Avalanche current (repetitive and non repetitive)		75	A
E_{AR}	Repetitive Avalanche Energy		30	mJ
Eas	Single Pulse Avalanche Energy		1500	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Electrical Characteristics (per MOSFET)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$			250	μA
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 35A$		19	21	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 1 \text{mA}$	2		4	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

Dynamic Characteristics (per MOSFET)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		5100		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		1900		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		800		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		200		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 100V$		40		nC
Q_{gd}	Gate – Drain Charge	$I_D = 70A$		92		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		35		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		70		ns
$T_{d(off)}$	Turn-off Delay Time	$\begin{array}{l} \begin{array}{l} \begin{array}{l} V_{Bus} = 66V \\ I_D = 70A \end{array} \end{array}$		95		
T_{f}	Fall Time	$R_G = 5\Omega$		125		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		276		Т
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 70A, R_G = 5\Omega$		302		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 70A, R_G = 5\Omega$		304		1
E _{off}	Turn-off Switching Energy			320		μJ
R_{thJC}	Junction to Case Thermal Resistance	ee			0.6	°C/W

Chopper diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					200	V
I_{RM}	Reverse Leakage Current	V _R =200V				250	μA
I_{F}	DC Forward Current		Tc = 80°C		60		A
	Diode Forward Voltage	$I_F = 60A$			1.1		
V_{F}		$I_F = 120A$	$I_F = 120A$		1.4		V
		$I_F = 60A$	$T_j = 125$ °C		0.9		
t_{rr}	Reverse Recovery Time	$I_{\rm F} = 60A$	$T_j = 25^{\circ}C$		31		ns
·rr		$V_R = 133V$	$V_R = 133V$ $T_j = 125$ °C		60		113
Qrr	Reverse Recovery Charge	di/dt	$T_j = 25$ °C		60		пC
ζm		=200A/μs	$T_j = 125$ °C		250		пС
R_{thJC}	Junction to Case Thermal Resistance					0.9	°C/W



Thermal and package characteristics

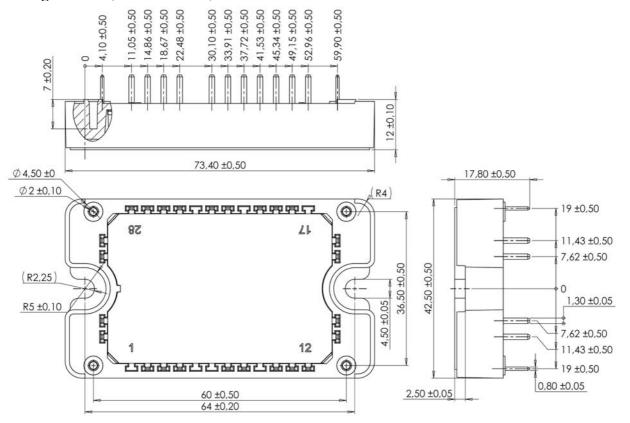
Symbol	Characteristic			Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
$T_{\rm J}$	Operating junction temperature range			-40	150	
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max - 25	°C
T_{STG}	Storage Temperature Range			-40	125	C
$T_{\rm C}$	Operating Case Temperature				125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic			Typ	Max	Unit
R ₂₅	Resistance @ 25°C	C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		$T_C=100$ °C		4		%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \begin{array}{l} \text{T: Thermistor temperature} \\ R_T: \text{ Thermistor value at T} \end{array}$$

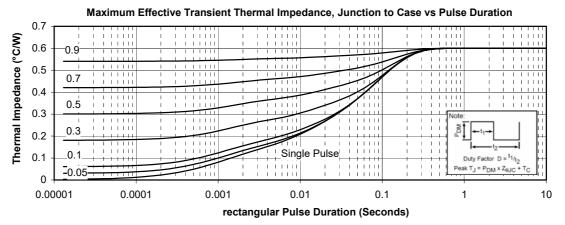
Package outline (dimensions in mm)

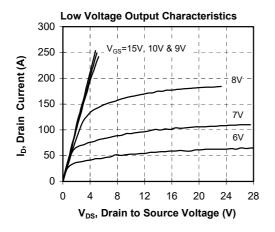


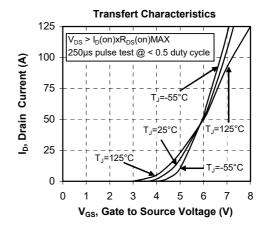
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

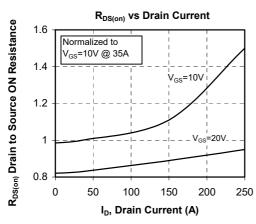


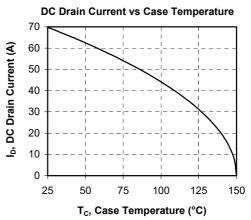
Typical Performance Curve



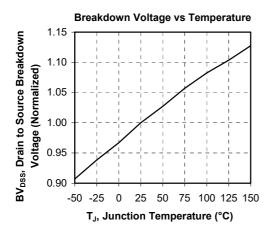


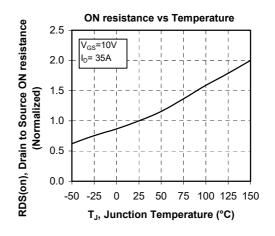


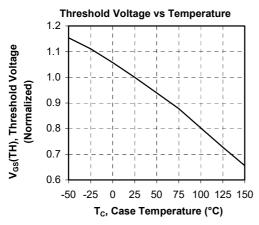


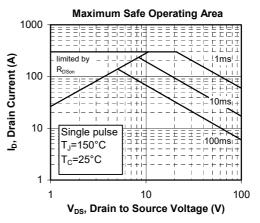


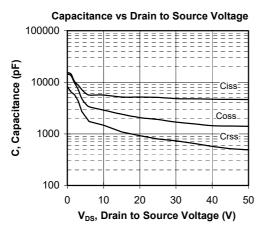


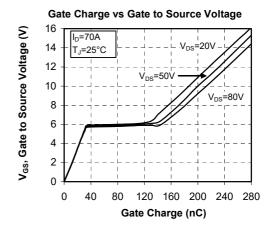




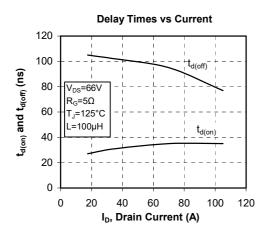


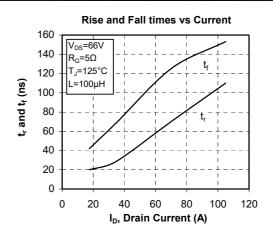


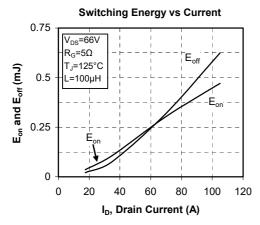


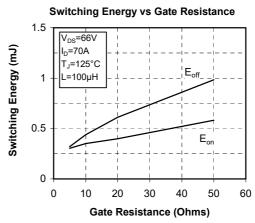


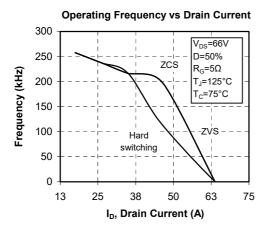


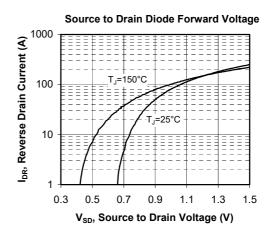












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